

RELAY DRIVERS, LAMP DRIVERS,
MOTOR DRIVERS AND STROBES APPLICATION.

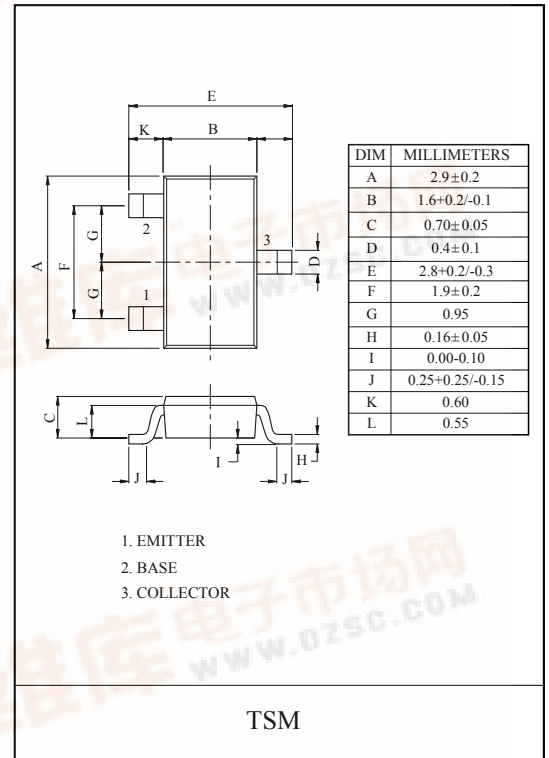
FEATURES

- Adoption of MBIT Processes.
- Large Current Capacitance.
- Low Collector-to-Emitter Saturation Voltage.
- High Speed Switching.
- Ultrasmall Package facilitates miniaturization in end products.
- High Allowable Power Dissipation.
- Complementary to KTC3544T.

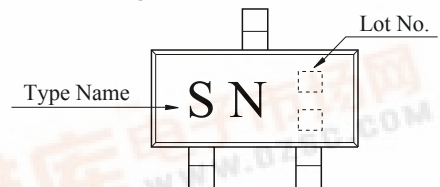
MAXIMUM RATING (Ta=25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Collector-Base Voltage		V _{CB0}	-30	V
Collector-Emitter Voltage		V _{CEO}	-30	V
Emitter-Base Voltage		V _{EBO}	-6	V
Collector Current	DC	I _C	-2	A
	Pulse	I _{CP}	-4	
Base Current		I _B	-400	mA
Collector Power Dissipation		P _C *	0.9	W
Junction Temperature		T _j	150	°C
Storage Temperature Range		T _{stg}	-55 ~ 150	°C

* Package mounted on a ceramic board (600mm² × 0.8mm)



Marking

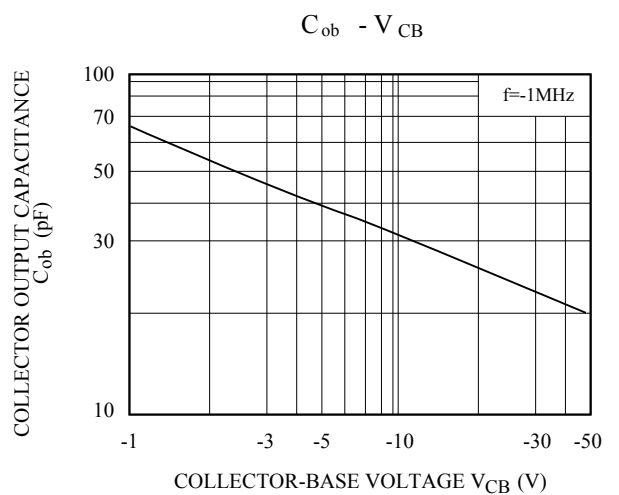
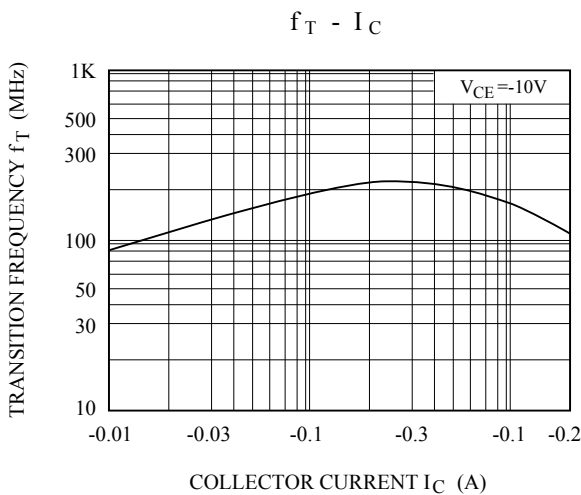
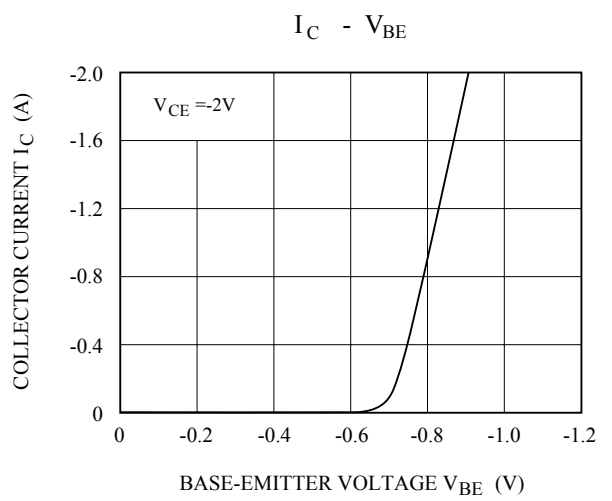
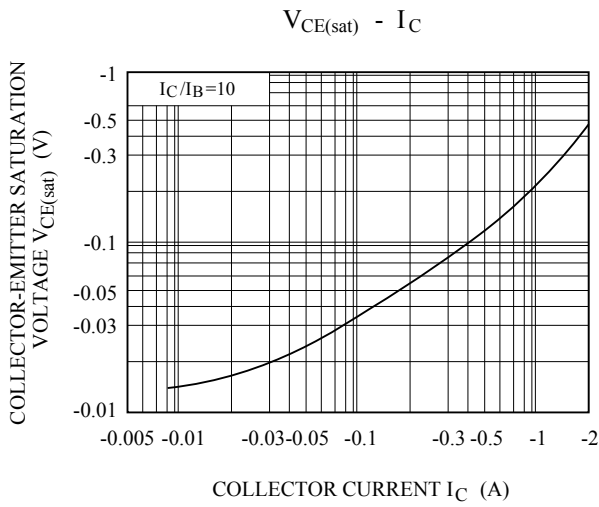
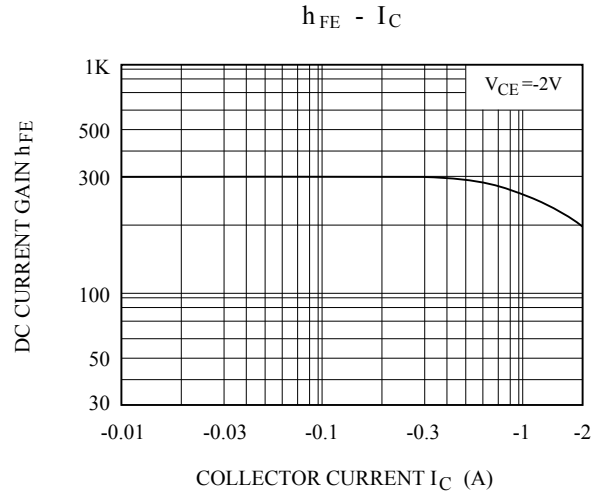
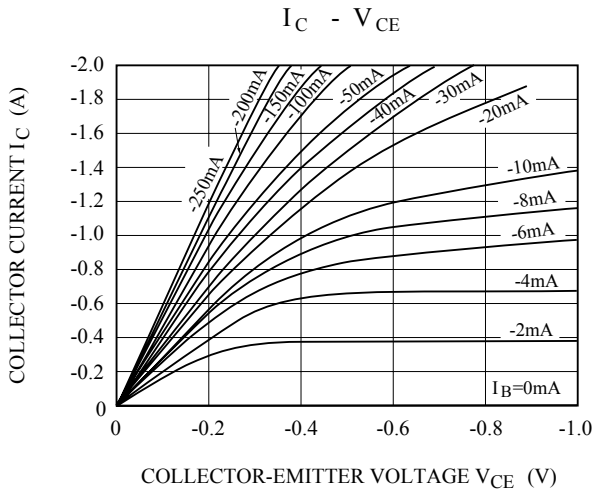


ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I _{CB0}	V _{CB} =-20V, I _E =0	-	-	-0.1	μA
Emitter Cut-off Current	I _{EBO}	V _{EB} =-3V, I _C =0	-	-	-0.1	μA
Collector-Base Breakdown Voltage	V _{(BR)CBO}	I _C =-10μA, I _E =0	-30	-	-	V
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	I _C =-1mA, I _B =0	-30	-	-	V
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	I _E =-10μA, I _C =0	-6	-	-	V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	I _C =-1.5A, I _B =-75mA	-	-350	-600	mV
Base-Emitter Saturation Voltage	V _{BE(sat)}	I _C =-1.5A, I _B =-75mA	-	-0.85	-1.2	V
DC Current Gain	h _{FE}	V _{CE} =-2V, I _C =-100mA	200	-	560	
Transition Frequency	f _T	V _{CE} =-10V, I _C =-50mA	-	150	-	MHz
Collector Output Capacitance	C _{ob}	V _{CB} =-10V, f=1MHz	-	32	-	pF
Switching Time	Turn-On Time	t _{on}	-	60	-	nS
	Storage Time	t _{stg}	-	350	-	
	Fall Time	t _f	-	25	-	

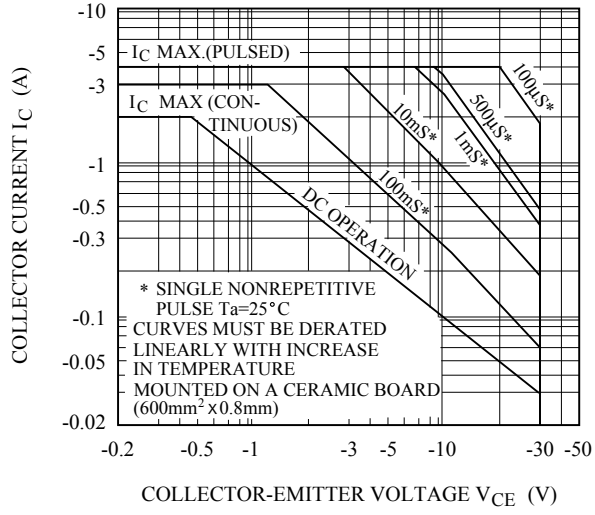


KTA1544T



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SAFE OPERATING AREA



$P_c - T_a$

